## MMBD6100LT1G

## Monolithic Dual Switching Diode

#### **Features**

 These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

## **MAXIMUM RATINGS (EACH DIODE)**

| Rating                     | Symbol                 | Value | Unit |
|----------------------------|------------------------|-------|------|
| Reverse Voltage            | V <sub>R</sub>         | 70    | Vdc  |
| Forward Current            | IF                     | 200   | mAdc |
| Peak Forward Surge Current | I <sub>FM(surge)</sub> | 500   | mAdc |

## THERMAL CHARACTERISTICS

| Characteristic                                      | Symbol                            | Max         | Unit        |
|---|-----------------------------------|-------------|-------------|
| Total Device Dissipation, FR-5 Board (Note 1)       | P <sub>D</sub>                    |             |             |
| T <sub>A</sub> = 25°C<br>Derate above 25°C          |                                   | 225<br>1.8  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient             | $R_{\theta JA}$                   | 556         | °C/W        |
| Total Device Dissipation Alumina Substrate (Note 2) | P <sub>D</sub>                    |             |             |
| T <sub>A</sub> = 25°C<br>Derate above 25°C          |                                   | 300<br>2.4  | mW<br>mW/°C |
| Thermal Resistance, Junction-to-Ambient             | $R_{\theta JA}$                   | 417         | °C/W        |
| Junction and Storage Temperature Range              | T <sub>J</sub> , T <sub>stg</sub> | -55 to +150 | °C          |

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- 1. FR-5 =  $1.0 \times 0.75 \times 0.062$  in.
- 2. Alumina = 0.4  $\times$  0.3  $\times$  0.024 in. 99.5% alumina.

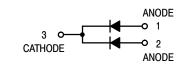
## $\textbf{ELECTRICAL CHARACTERISTICS} \ (T_A = 25^{\circ}C \ unless \ otherwise \ noted)$

| Characteristic   | Symbol            | Min         | Max        | Unit |  |
|--|-------------------|-------------|------------|------|--|
| OFF CHARACTERISTICS  |                   |             |            |      |  |
| Reverse Breakdown Voltage (I <sub>(BR)</sub> = 100 μAdc)   | V <sub>(BR)</sub> | 70          | -          | Vdc  |  |
| Reverse Voltage Leakage Current (V <sub>R</sub> = 50 Vdc) (For each individual diode while the second diode is unbiased) | I <sub>R</sub>    | -           | 0.1        | μAdc |  |
| Forward Voltage<br>(I <sub>F</sub> = 1.0 mAdc)<br>(I <sub>F</sub> = 100 mAdc)  | V <sub>F</sub>    | 0.55<br>0.8 | 0.7<br>1.1 | Vdc  |  |
| Reverse Recovery Time $(I_F = I_R = 10 \text{ mAdc}, I_{R(REC)} = 1.0 \text{ mAdc})$ (Figure 1)                          | t <sub>rr</sub>   | -           | 4.0        | ns   |  |
| Capacitance (V <sub>R</sub> = 0 V)   | С                 | -           | 2.5        | рF   |  |



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SOT-23 CASE 318 STYLE 9

## **MARKING DIAGRAM**



5B = Specific Device Code

M = Date Code\*

= Pb-Free Package

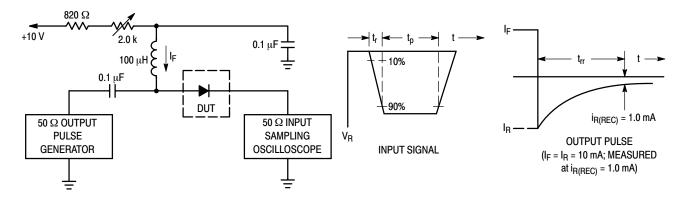
(Note: Microdot may be in either location)
\*Date Code orientation and/or overbar may
vary depending upon manufacturing location.

## **ORDERING INFORMATION**

|              |                     | İ                     |
|--------------|---------------------|-----------------------|
| Device       | Package             | Shipping <sup>†</sup> |
| MMBD6100LT1G | SOT-23<br>(Pb-Free) | 3000/Tape & Reel      |
| MMBD6100LT3G | SOT-23<br>(Pb-Free) | 10,000/Tape & Reel    |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

## MMBD6100LT1G



Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current (I<sub>F</sub>) of 10 mA.

- 2. Input pulse is adjusted so  $I_{R(peak)}$  is equal to 10 mA.
- 3.  $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

## **CURVES APPLICABLE TO EACH CATHODE**

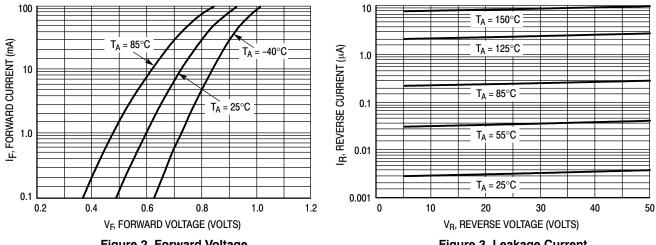


Figure 2. Forward Voltage

Figure 3. Leakage Current

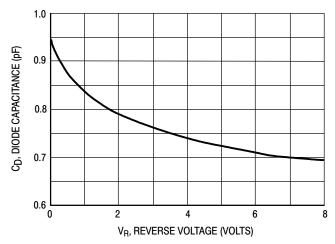
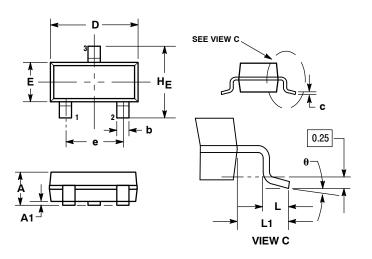


Figure 4. Capacitance

## MMBD6100LT1G

#### PACKAGE DIMENSIONS

**SOT-23 (TO-236)** CASE 318-08 ISSUE AN



#### NOTES:

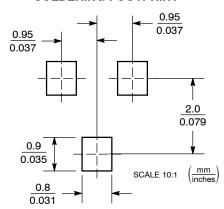
- DIMENSIONING AND TOLERANCING PER
- ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.
  3. MAXIMUM LEAD THICKNESS INCLUDES
  LEAD FINISH THICKNESS. MINIMUM LEAD
  THICKNESS IS THE MINIMUM THICKNESS OF
- BASE MATERIAL.
  4. 318-01 THRU -07 AND -09 OBSOLETE, NEW STANDARD 318-08.

|     | MILLIMETERS |      |      | INCHES |       |       |
|-----|-------------|------|------|--------|-------|-------|
| DIM | MIN         | NOM  | MAX  | MIN    | NOM   | MAX   |
| Α   | 0.89        | 1.00 | 1.11 | 0.035  | 0.040 | 0.044 |
| A1  | 0.01        | 0.06 | 0.10 | 0.001  | 0.002 | 0.004 |
| b   | 0.37        | 0.44 | 0.50 | 0.015  | 0.018 | 0.020 |
| С   | 0.09        | 0.13 | 0.18 | 0.003  | 0.005 | 0.007 |
| D   | 2.80        | 2.90 | 3.04 | 0.110  | 0.114 | 0.120 |
| E   | 1.20        | 1.30 | 1.40 | 0.047  | 0.051 | 0.055 |
| е   | 1.78        | 1.90 | 2.04 | 0.070  | 0.075 | 0.081 |
| L   | 0.10        | 0.20 | 0.30 | 0.004  | 0.008 | 0.012 |
| L1  | 0.35        | 0.54 | 0.69 | 0.014  | 0.021 | 0.029 |
| HE  | 2.10        | 2.40 | 2.64 | 0.083  | 0.094 | 0.104 |

#### STYLE 9:

- PIN 1. ANODE
  - 2. ANODE
  - 3. CATHODE

#### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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